

10/526059

DT01 Rec'd PCT/PTC 28 FEB 2005

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of:

Ellison et al.

Application No.: U.S. National Phase of  
PCT/SE2003/001309

Filed: herewith

: Attorney Docket: 35947-213490

: Art Unit: to be assigned

: Examiner: to be assigned

Title: LIGHTLY DOPED SILICON CARBIDE WAFER AND USE THEREOF IN HIGH  
POWER DEVICES

PRELIMINARY AMENDMENT

Commissioner for Patents  
P.O. Box 1450  
Alexandria, Virginia 22313-1450

Sir:

Prior to examination, please amend the above-identified application as follows: